EV4415M-QB-00A

High Efficiency 1.5A, 36V, 2.2MHz
Synchronous Step Down Convertor Evaluation Board

The Future of Analog IC Technology

DESCRIPTION

The EV4415M-QB-00A is an evaluation board for the MP/MPQ4415MGQB.

MP/MPQ4415MGQB is a synchronous, rectified, step-down, switch-mode convertor with built-in power MOSFETs and one input bypass capacitor. It offers a very compact solution to achieve a 1.5A of continuous output current with excellent load and line regulation over a wide input supply range. The MP/MPQ4415M uses synchronous mode operation to achieve high efficiency over the output current load range.

The EV4415M-QB-00A is a fully assembled and tested evaluation board, it generates 3.3V output voltage at load current up to 1.5A from a 4V to 36V input range.

ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Value	Units
Input Voltage	V_{IN}	4 – 36	V
Output Voltage	V_{OUT}	3.3	V
Output Current	I_{OUT}	1.5	A

FEATURES

- Wide 4V to 36V Operating Input Range
- 1.5A Continuous Load Current
- 90mΩ High-Side, 50mΩ Low-Side Internal Power MOSFETs
- High-Efficiency Synchronous Mode Operation
- Default 2.2MHz Switching Frequency
- 450kHz to 2.2MHz Frequency Sync
- Forced Continuous Conduction Mode (CCM)
- Internal Soft Start (SS)
- Power Good (PG) Indicator
- Over-Current Protection (OCP) with Valley-Current Detection and Hiccup
- Thermal Shutdown
- Output Adjustable from 0.8V
- Available in a QFN-13 (2.5mmx3mm) Package
- CISPR25 Class 5 Compliant
- AEC-Q100 Grade-1

APPLICATIONS

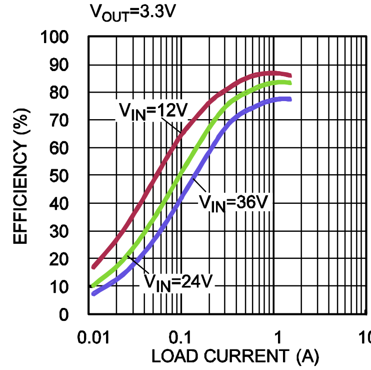
- Automotive
- Industrial Control Systems
- Medical and Imaging Equipment
- Telecom Applications
- Distributed Power Systems

EVALUATION BOARD

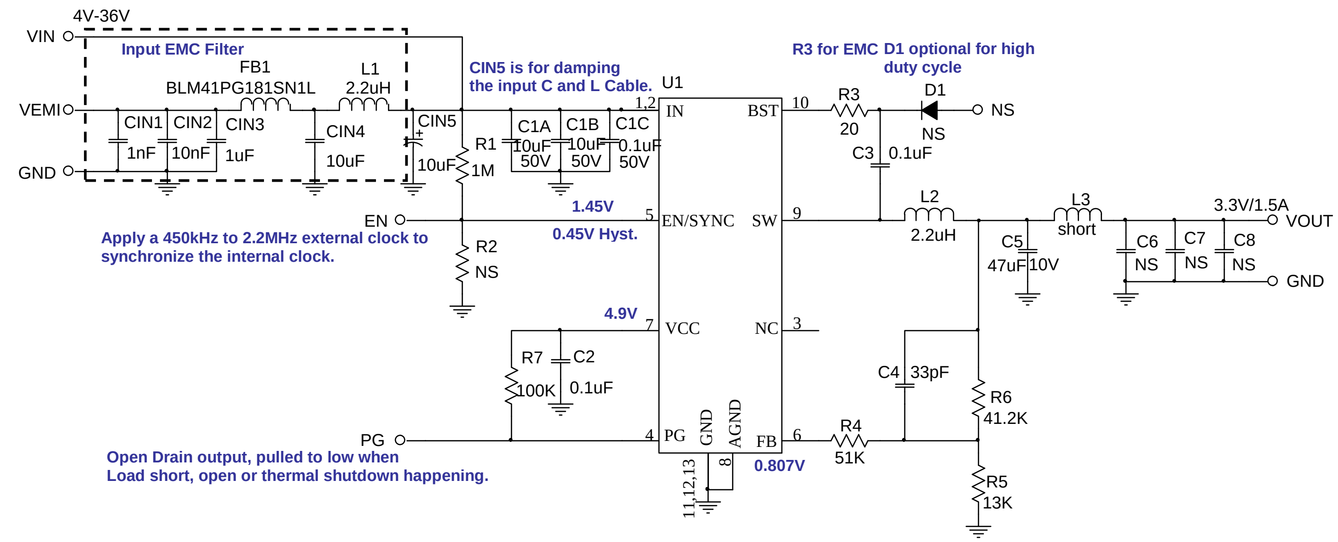
(L x W x H) 2.5" x 2.5" x 0.4"
(6.4cm x 6.4cm x 1.0cm)

Board Number	MPS IC Number
EV4415M-QB-00A	MP/MPQ4415MGQB

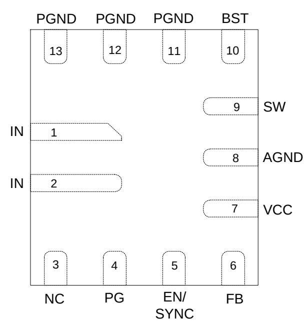
Efficiency vs. Load Current
V_{OUT}=3.3V



EVALUATION BOARD SCHEMATIC



Package reference



Reference for FB divider selection

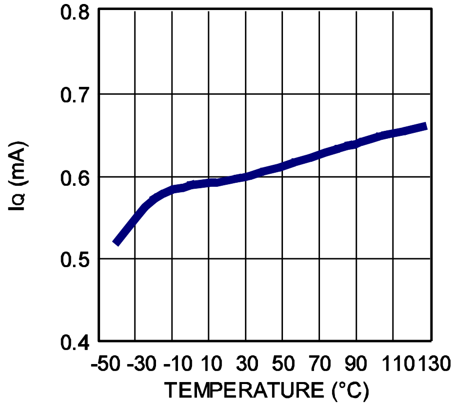
Vo(V)	R6(kΩ)	R5(kΩ)
5	41.2(1%)	7.68(1%)
2.5	41.2(1%)	19.6(1%)
1.8	41.2(1%)	33.5(1%)

EV4415M-QB-00A BILL OF MATERIALS

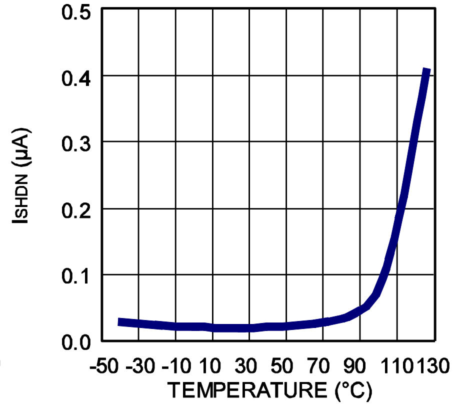
Qty	Ref	Value	Description	Package	Manufacturer	Part Number
5	CIN1,CIN5	NS				
2	C1A, C1B	10μF	Ceramic Cap., 50V, X5R	1206	muRata	GRM31CR61H106KA12L
1	C1C	0.1μF	Ceramic Cap., 50V, X7R	0603	muRata	GRM188R71H104KA93D
2	C2, C3	0.1μF	Ceramic Cap., 16V, X7R	0603	muRata	GRM188R71C104KA01D
1	C4	33pF	Ceramic Cap., 50V, C0G	0603	muRata	GRM1885C1H330JA01D
1	C5	47μF	Ceramic Cap., 10V, X5R	1210	muRata	GRM32ER61A476KE20L
3	C6, C7, C8	NS				
1	D1	NS				
1	FB1	NS				
1	L1	NS				
1	L2	2.2μH	Inductor, 82mOhm DCR, 3.3A	SMD	TOKO	DFE252012F-2R2MP2
1	L3	Short				
1	R1	1M	Film Res., 5%	0603	Yageo	RC0603JR-071ML
1	R3	20	Film Res., 1%	0603	Yageo	RC0603FR-0720RL
1	R4	51k	Film Res., 1%	0603	Yageo	RC0603FR-0751KL
1	R5	13k	Film Res., 1%	0603	Yageo	RC0603FR-0713KL
1	R6	41.2k	Film Res., 1%	0603	Yageo	RC0603FR-0741K2L
1	R7	100k	Film Res., 1%	0603	Yageo	RC0603FR-07100KL
1	R2	NS				
1	U1		Step-Down Regulator	QFN13(2X3)	MPS	MPQ4415MGQB
5	VIN, VEMI, GND, GND, VOUT		2.0 Golden Pin		HZ	
4	PG, GND, EN/ SYNC, GND		2.54mm Test Pin		HZ	

TYPICAL CHARACTERISTICS

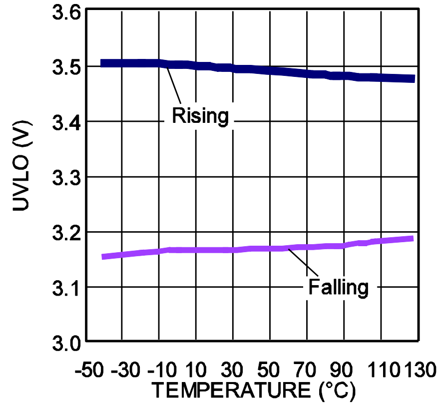
Quiescent Current vs. Temperature



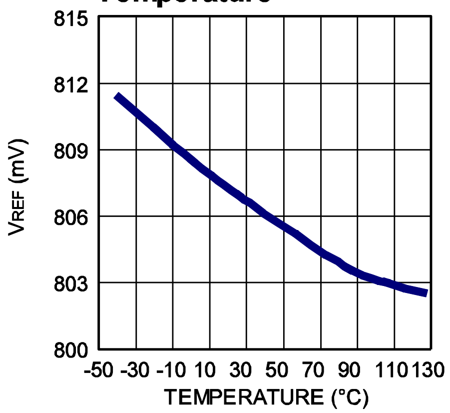
Shutdown Current vs. Temperature



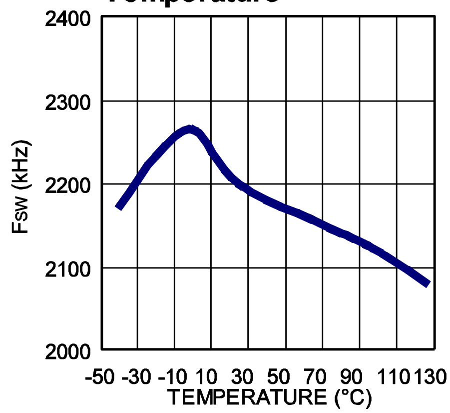
VIN UVLO Threshold vs. Temperature



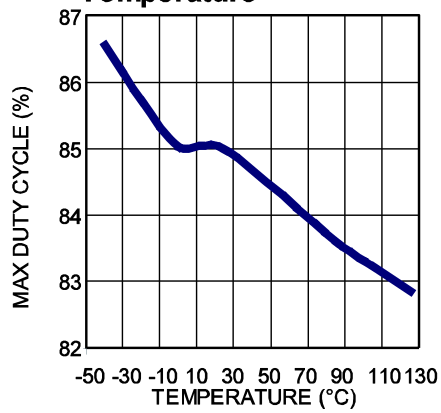
Feedback Reference vs. Temperature



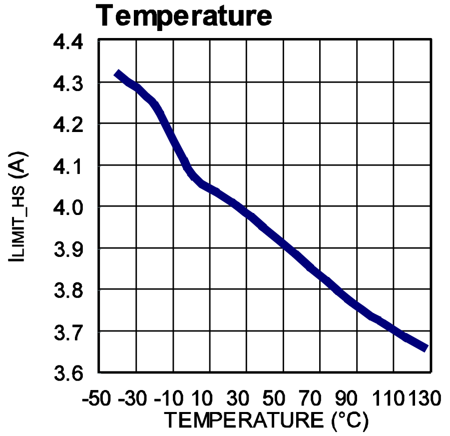
Switching Frequency vs. Temperature



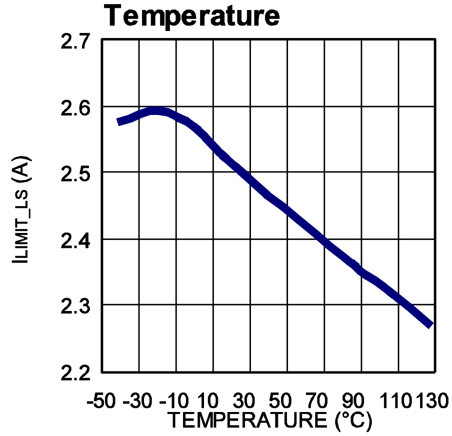
Max Duty Cycle vs. Temperature



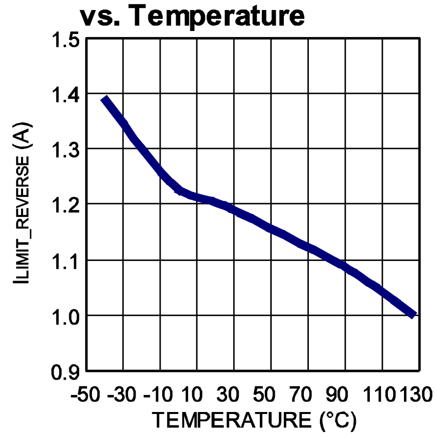
Current Limit vs. Temperature



Valley Current Limit vs. Temperature

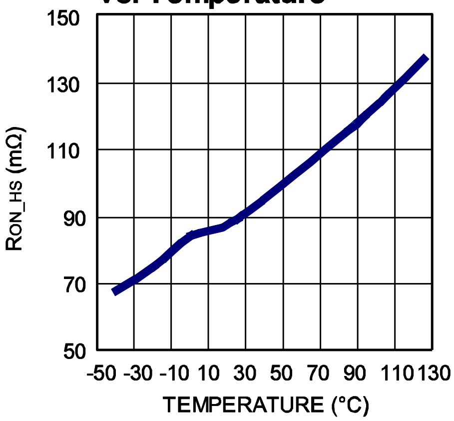


Reverse Current Limit vs. Temperature

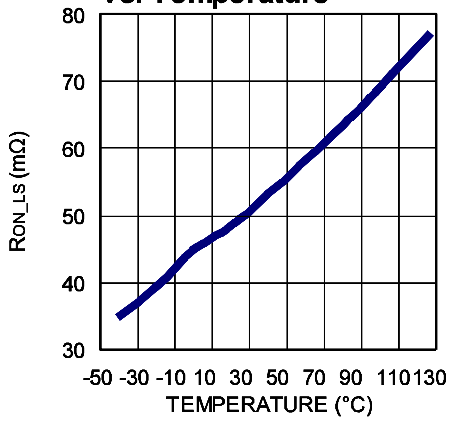


TYPICAL CHARACTERISTICS *(continued)*

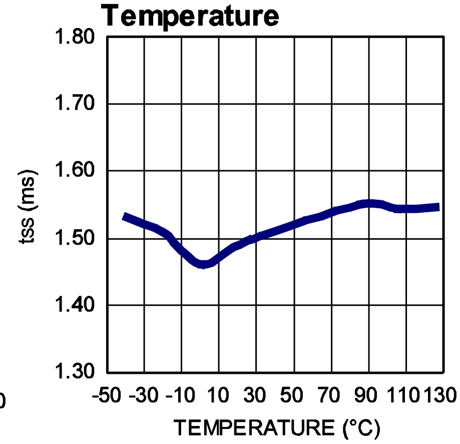
HS-FET On Resistance vs. Temperature



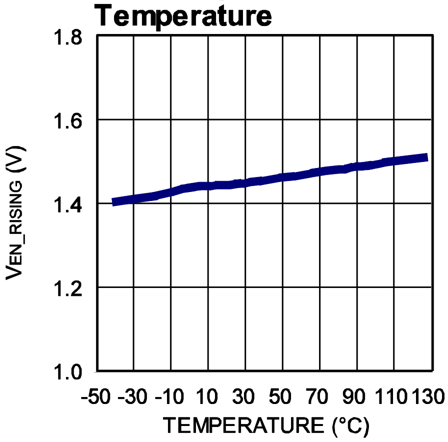
LS-FET On Resistance vs. Temperature



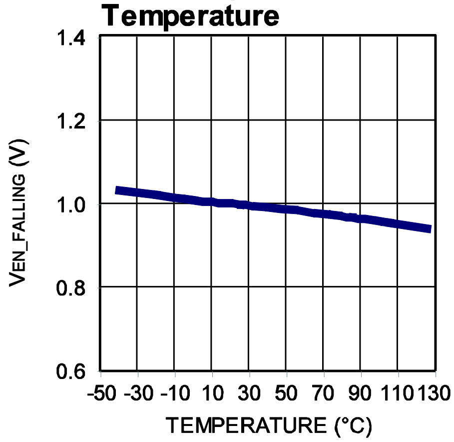
Soft-Start Time vs. Temperature



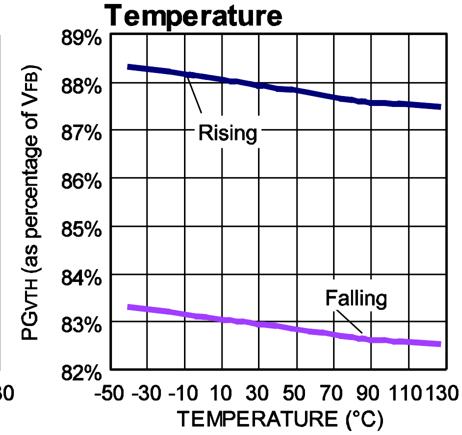
EN Rising Threshold vs. Temperature



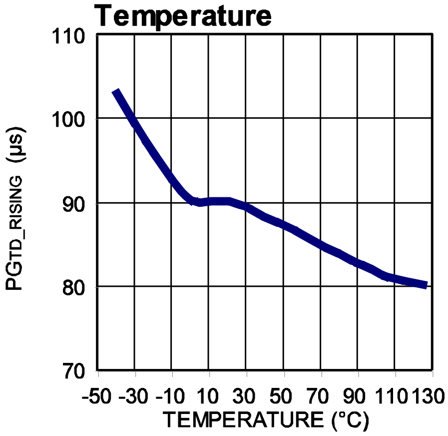
EN Falling Threshold vs. Temperature



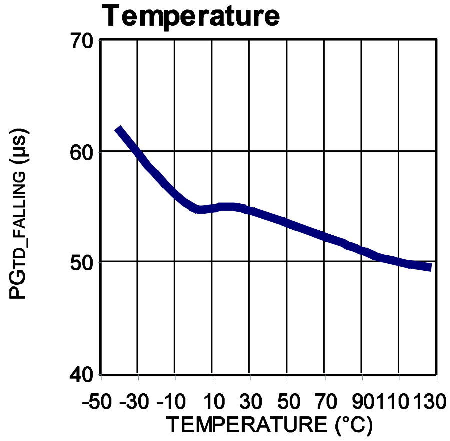
PG Threshold vs. Temperature



PG Rising Delay vs. Temperature



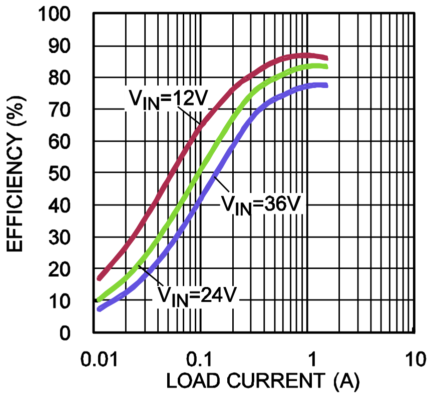
PG Falling Delay vs. Temperature



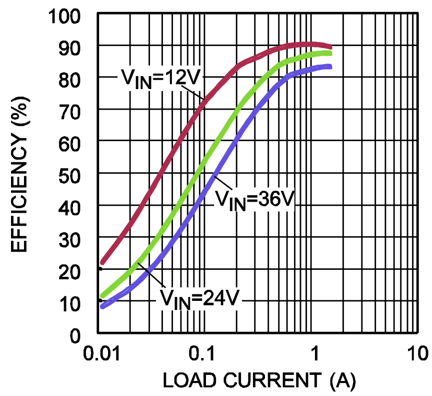
EVB TEST RESULTS

Performance waveforms are tested on the evaluation board.
V_{IN} = 12V, V_{OUT} =3.3V, L=2.2µH, F_{SW}=2.2MHz, T_A = +25°C, unless otherwise noted.

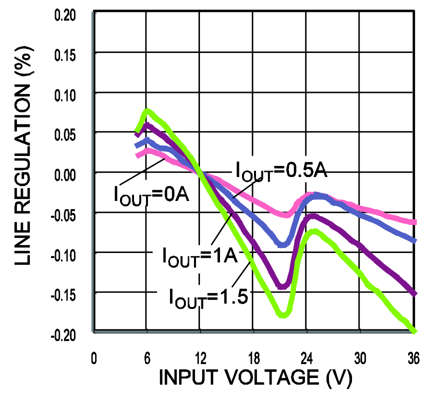
Efficiency vs. Load Current
V_{OUT}=3.3V



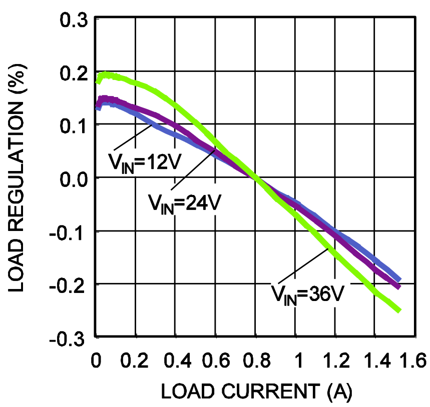
Efficiency vs. Load Current
V_{OUT}=5V



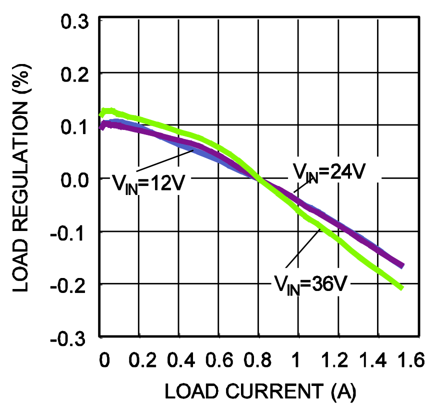
Line Regulation
V_{OUT}=3.3V



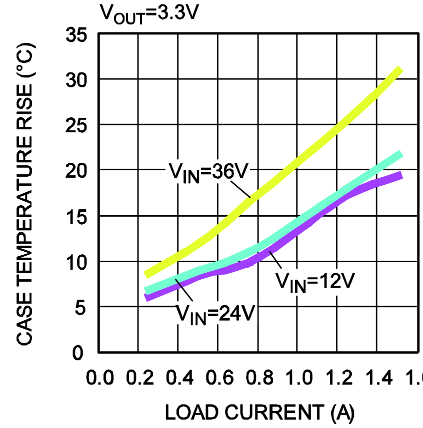
Load Regulation
V_{OUT}=3.3V



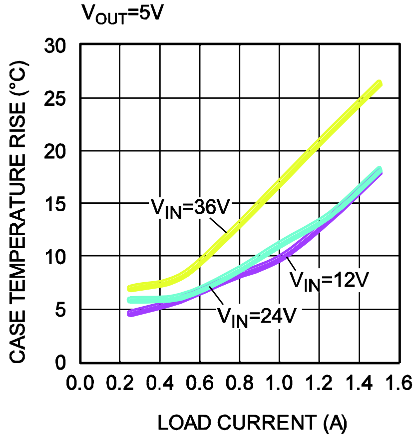
Load Regulation
V_{OUT}=5V



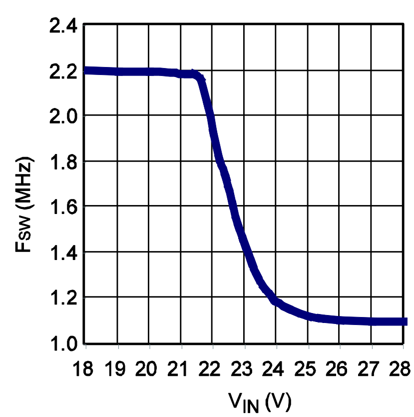
Case Temperature Rise vs. Load Current
V_{OUT}=3.3V



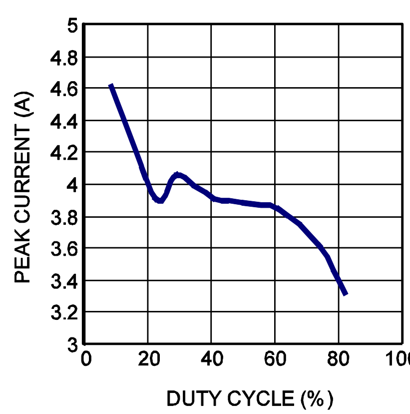
Case Temperature Rise vs. Load Current
V_{OUT}=5V



Frequency vs. V_{IN}



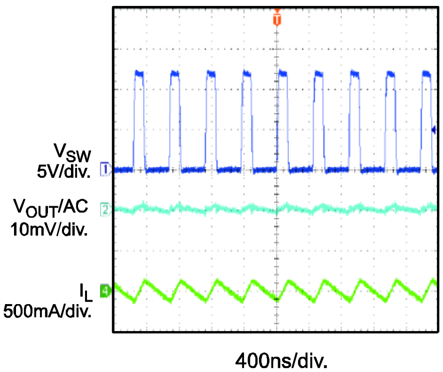
Peak Current vs. Duty Cycle



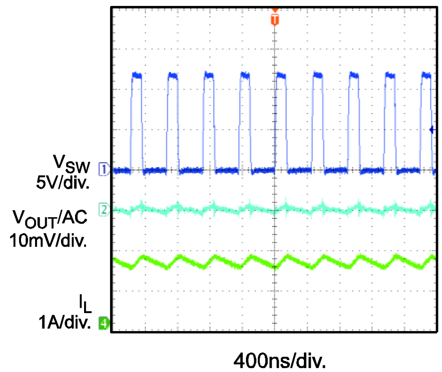
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{IN} = 12V, V_{OUT} =3.3V, L=2.2µH, F_{SW}=2.2MHz, T_A = +25°C, unless otherwise noted.

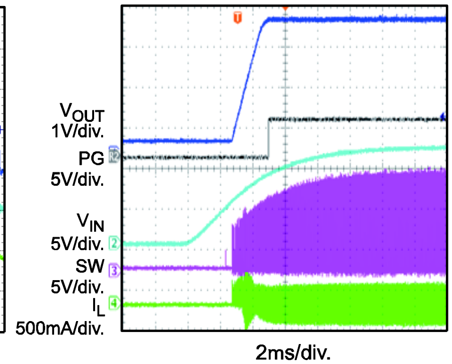
Steady State
I_{OUT}=0A



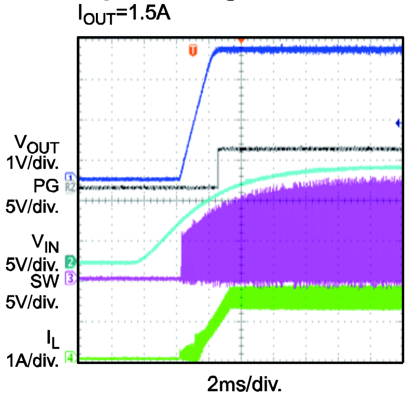
Steady State
I_{OUT}=1.5A



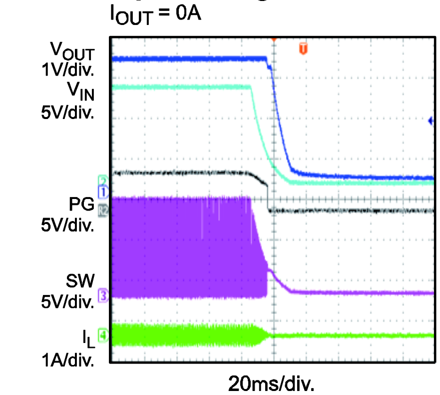
Start-Up through Input Voltage
I_{OUT}=0A



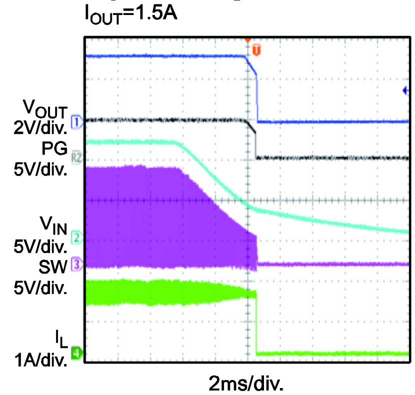
Start-Up through Input Voltage
I_{OUT}=1.5A



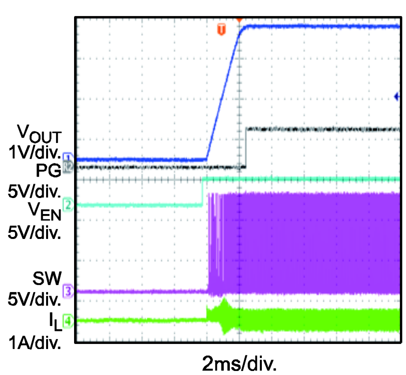
Shutdown through Input Voltage
I_{OUT} = 0A



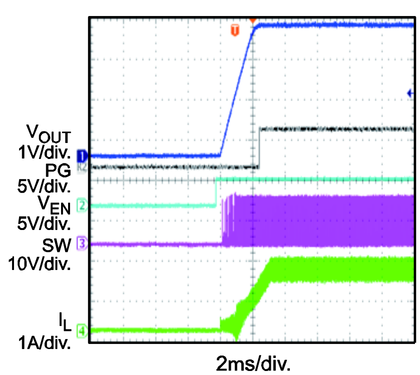
Shutdown through Input Voltage
I_{OUT}=1.5A



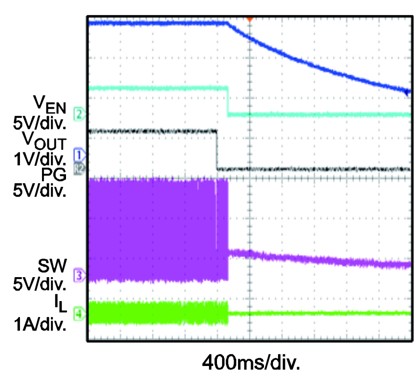
Start-Up through Enable
I_{OUT} = 0A



Start-Up through Enable
I_{OUT}=1.5A



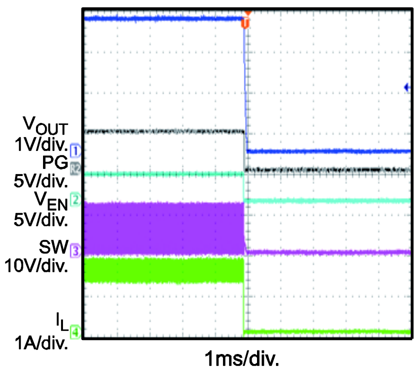
Shutdown through Enable
I_{OUT} = 0A



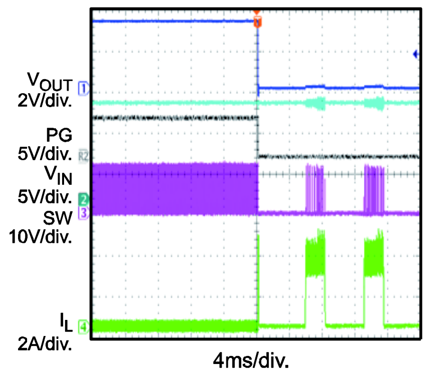
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{IN} = 12V, V_{OUT} =3.3V, L=2.2µH, F_{SW}=2.2MHz, T_A = +25°C, unless otherwise noted.

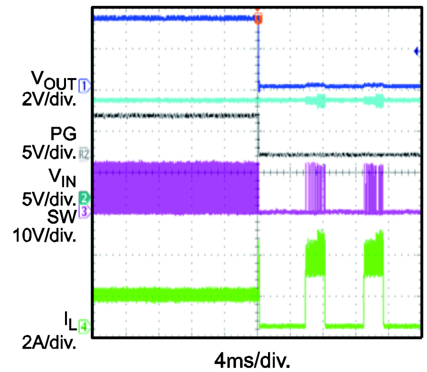
Shutdown through Enable
I_{OUT} = 1.5A



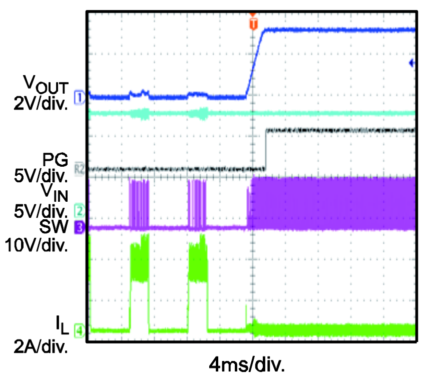
SCP Entry
I_{OUT} = 0A



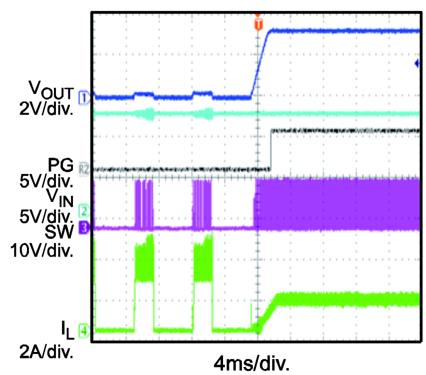
SCP Entry
I_{OUT} = 1.5A



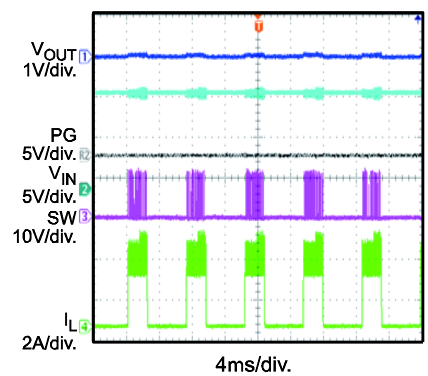
SCP Recovery
I_{OUT} = 0A



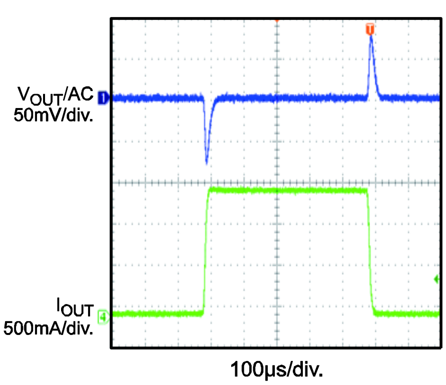
SCP Recovery
I_{OUT} = 1.5A



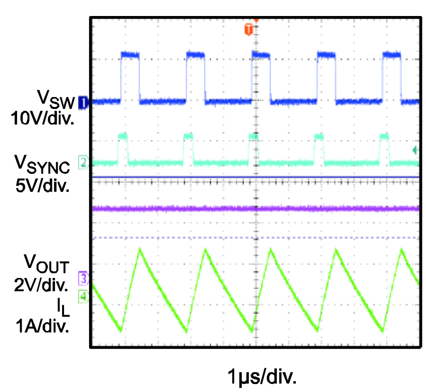
SCP Steady State



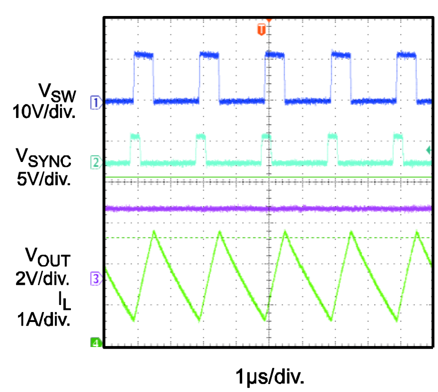
Load Transient
I_{OUT} = 0A-1.5A



SYNC Operation
f_{SYNC}=500kHz, D=15%, I_{OUT}=0A



SYNC Operation
f_{SYNC}=500kHz, D=15%, I_{OUT}=1.5A



PRINTED CIRCUIT BOARD LAYOUT

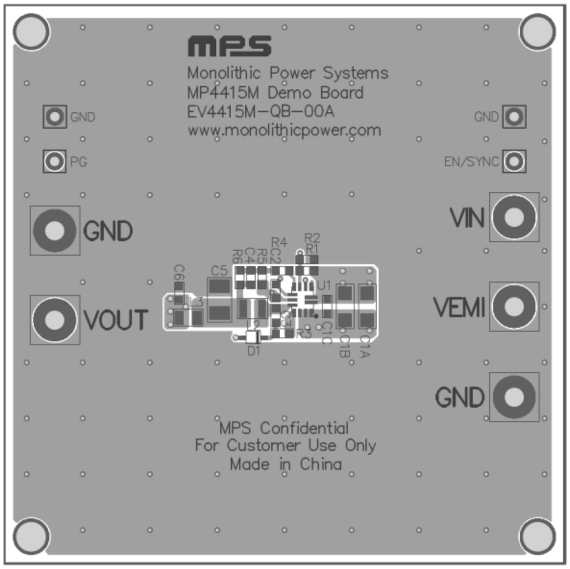


Figure 1—Top Silk Layer and Top Layer

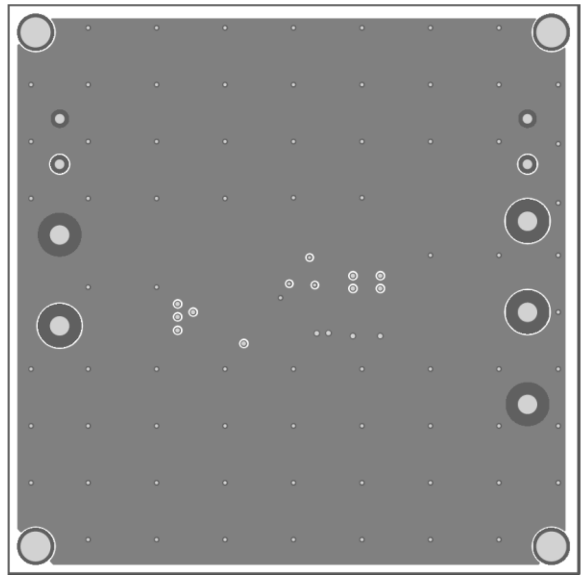


Figure 2—Inner1 Layer

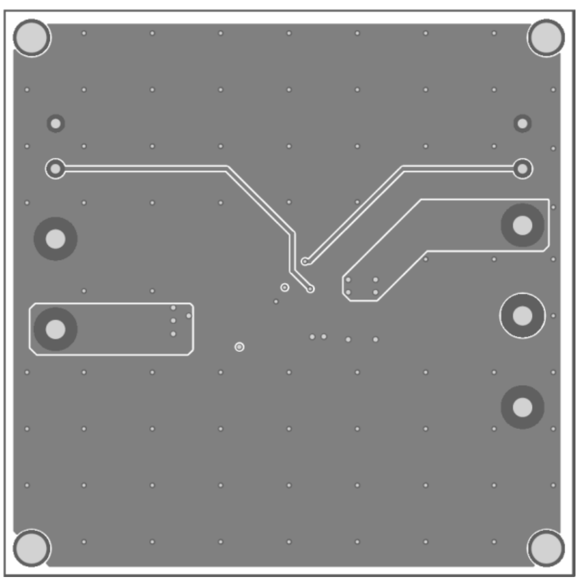


Figure 3—Inner2 Layer

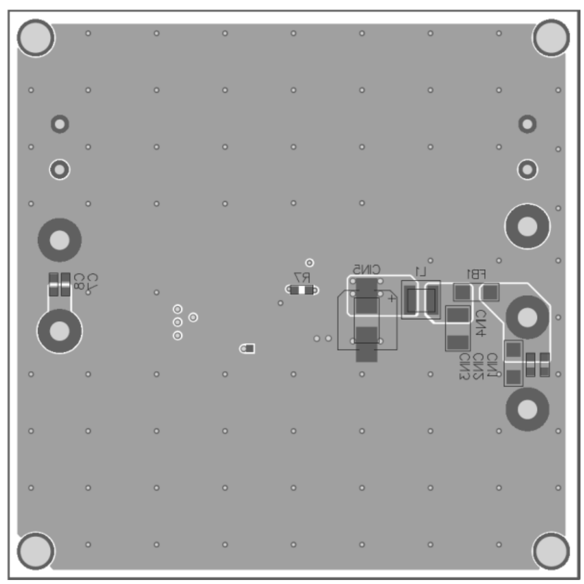


Figure 4—Bottom Silk Layer and Bottom Layer

QUICK START GUIDE

1. Connect the positive and negative terminals of the load to the VOUT and GND pins, respectively.

   Be aware that electronic loads represent a negative impedance to the regulator and if set to a too high current will trigger Hiccup mode.

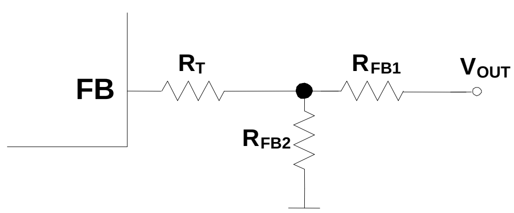
2. Preset the power supply output to between 4 and 36V, and then turn it off.

   If longer cables are used between the source and the EVB (>0.5m total), a damping capacitor should be installed at the input terminals. Especially when Vin is ≥ 24V.

3. Connect the positive and negative terminals of the power supply output to the VIN and GND pins, respectively.
4. Turn the power supply on. The MP/MPQ4415MGQB will automatically startup.
5. To use the Enable function, apply a digital input to the EN/Sync pin. Drive EN higher than 1.45V to turn on the regulator, drive EN less than 1V to turn it off.
6. To use the Sync function, apply a 450kHz to 2.2MHz external clock to the EN/Sync pin to synchronize the internal clock rising edge.
7. The output voltage is set by the external resistor divider. The feedback resistor (R_{FB1}) also sets the feedback loop bandwidth with the internal compensation capacitor. Choose R_{FB1} to be around 40kΩ when $V_{OUT} \geq 1V$. R_{FB2} can then be calculated with below equation:

$$R_{FB2} = \frac{R_{FB1}}{\frac{V_{OUT}}{0.807V} - 1}$$

8. The T-type network is highly recommended when V_{OUT} is low.



9. R_T + R_{FB1} is used to set the loop bandwidth. The lower R_T +R_{FB1} is, the higher the bandwidth. However, a high bandwidth may cause an insufficient phase margin, resulting in loop unstable. Therefore, a proper R_T value is required to make a trade-off between bandwidth and phase margin. Below table lists the recommended feedback resistor and R_T values for common output voltages.

V_{OUT} (V)	R_{FB1} (kΩ)	R_{FB2} (kΩ)	R_T (kΩ)
3.3	41.2 (1%)	13 (1%)	51 (1%)
5	41.2 (1%)	7.68 (1%)	51 (1%)